MAINTENANCE MANUAL 851-870 MHz, 110 WATT POWER AMPLIFIER 19D902797G5

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DESCRIPTION

The 800 MHz MASTR III Power Amplifier Assembly is a wide band RF power amplifier operating over the 851-870 MHz range without tuning. Its main function is to amplify the 10 mW FM signal from the Transmitter Synthesizer to the rated RF output at the antenna port. The output of the Power Amplifier Assembly is adjustable from rated power to 10dB below rated power at the PA output J104.

The assembly consists of a printed wiring board (A1) and associated components, including a power module

and an RF power transistor, mounted to the heat sink assembly. The printed wiring board (A1) contains both the power amplifier circuitry and the power control circuitry. The heatsink assembly includes a copper heat spreader for the power transistor.

Unfiltered supply voltage, A+, for the power amplifier circuits enters the assembly via feedthrough capacitor, C1. Power cable W4 routes the A+ from C1 to J103 on the PWB. Filtered A+ voltage for the power control circuit enters the assembly via control cable W13 which connects to the PWB at J201.

PA FAN PLATE ASSEMBLY 188D6127G1

SYMBOL	PART NO.	DESCRIPTIO
4	SBS 123 01/10	Spring nut.
5	19A702339P510	Screw, thread formin flat head.
6	19A701312P5	Washer, plain steel, 3 mm.
7	19A702381P510	Screw, thread formin pan head.
9	19A700136P19	Sleeve
10	105 8567/1	Guard, fan.
11	19A701863P12	Clamp, loop.
13	19A700033P6	Washer, lock, ext too
14	19A700034P5	Nut, hex, steel.
B1 and B2	BKV 301 216/02	DC fan.
W1	344A3337P4	Cable.
WT1 and WT2	7142645P1	Conductor, splice.

Ericsson Inc. Private Radio Systems Mountain View Road Lynchburg, Virginia 24502 1-800-528-7711 (Outside USA, 804-528-7711)



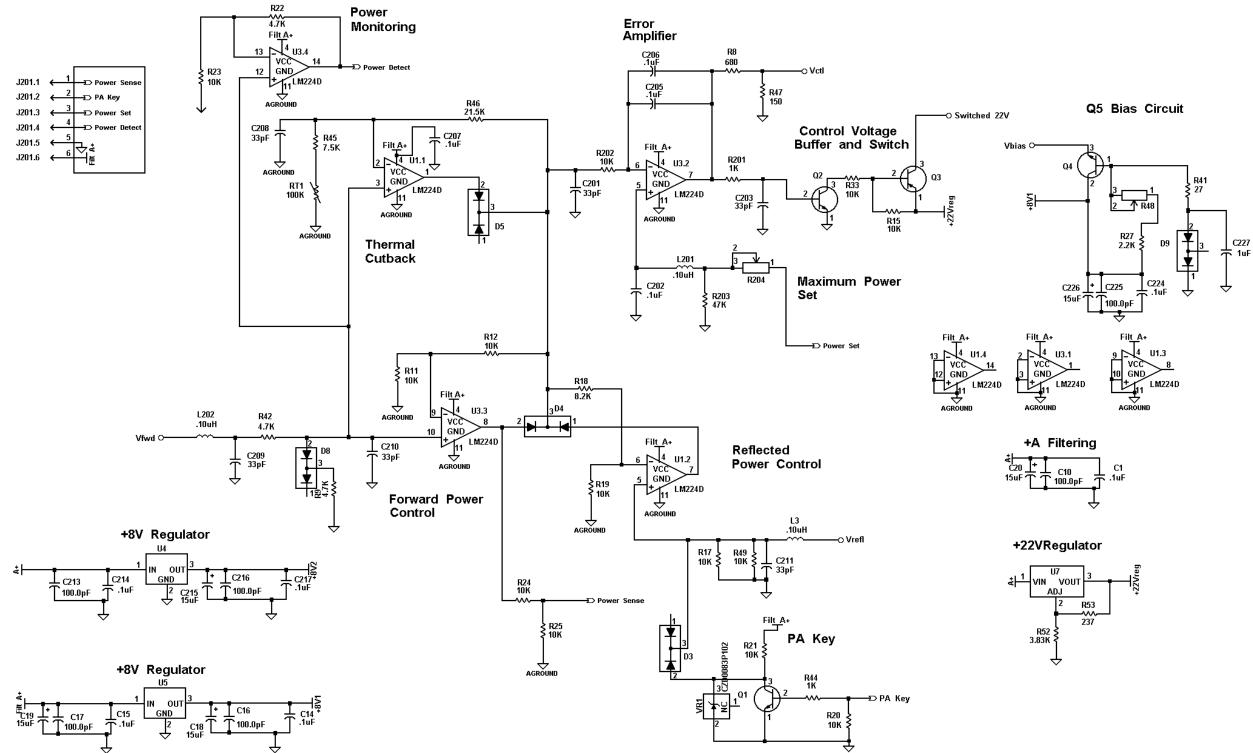
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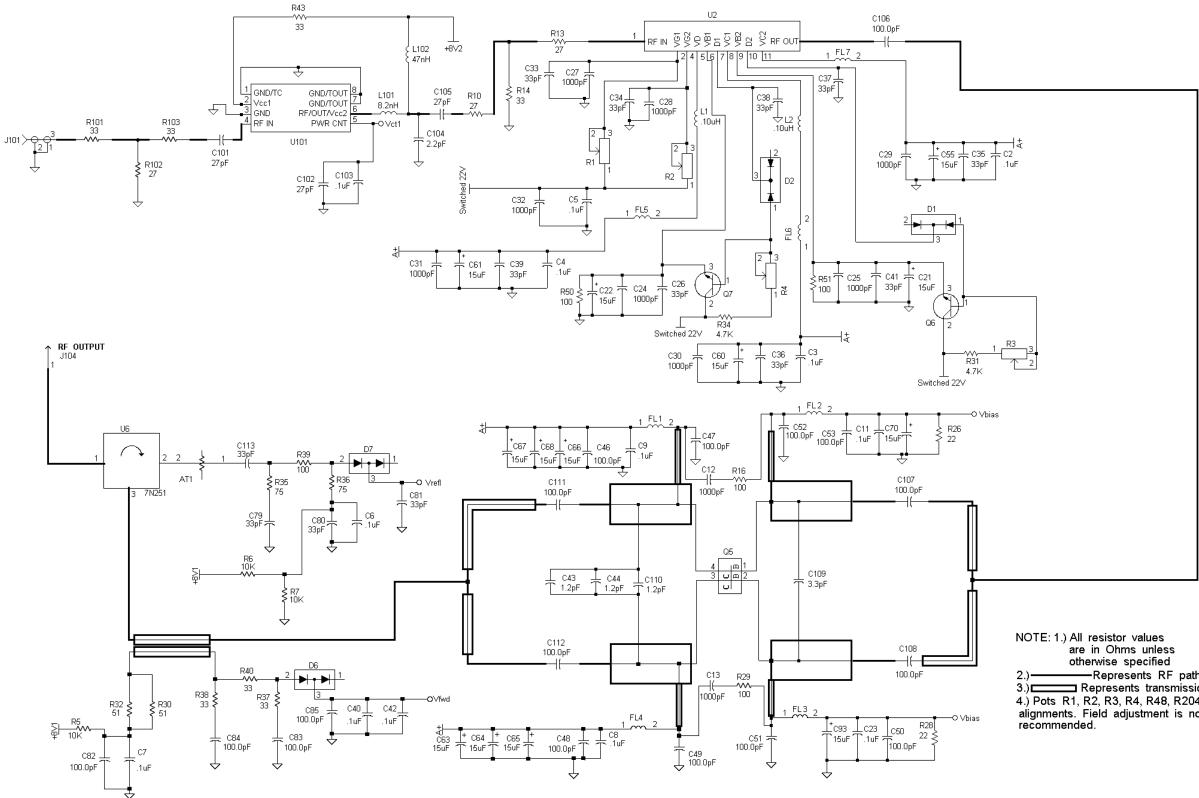
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POWER AMPLIFIER BOARD A1 19D902794G5

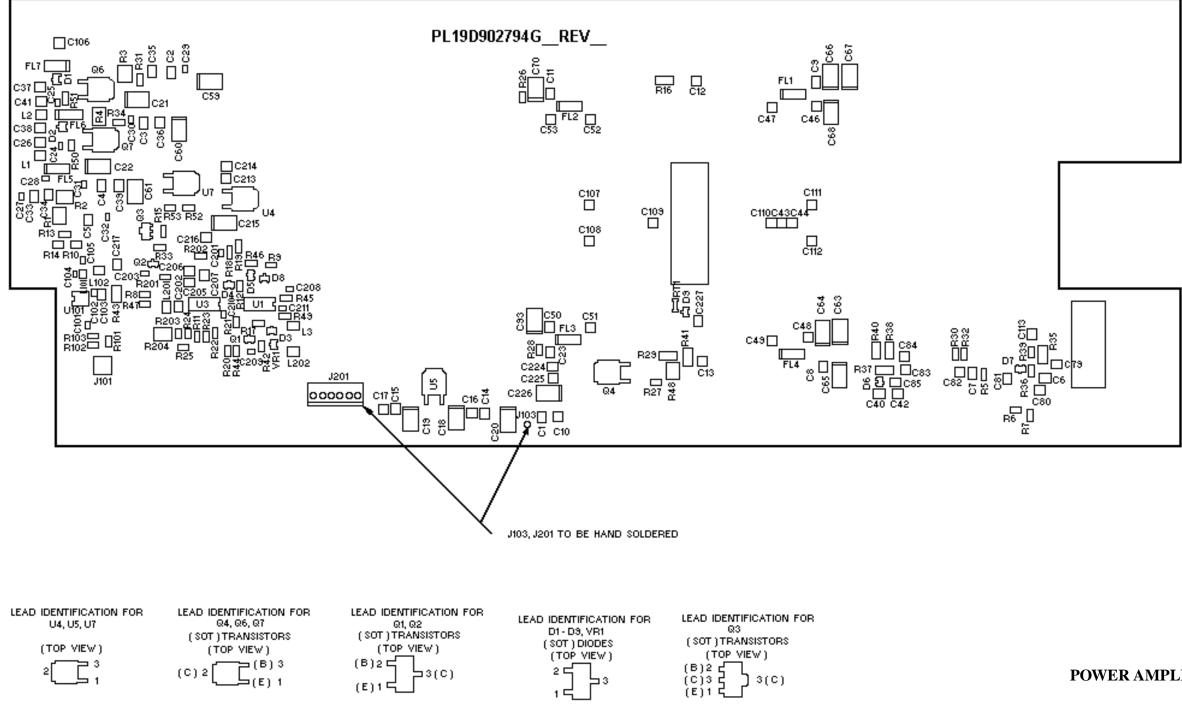
(188D5792, Sh.2, Rev. 1)



POWER AMPLIFIER ASSEMBLY 19D902797G5

(188D5792, Sh. 1, Rev. 1)

-Represents RF path. 3.) Represents transmission line. 4.) Pots R1, R2, R3, R4, R48, R204 are factory alignments. Field adjustment is not



POWER AMPLIFIER BOARD A1 19D902794G5

(19d902794 Sh. 3, Rev. 0)

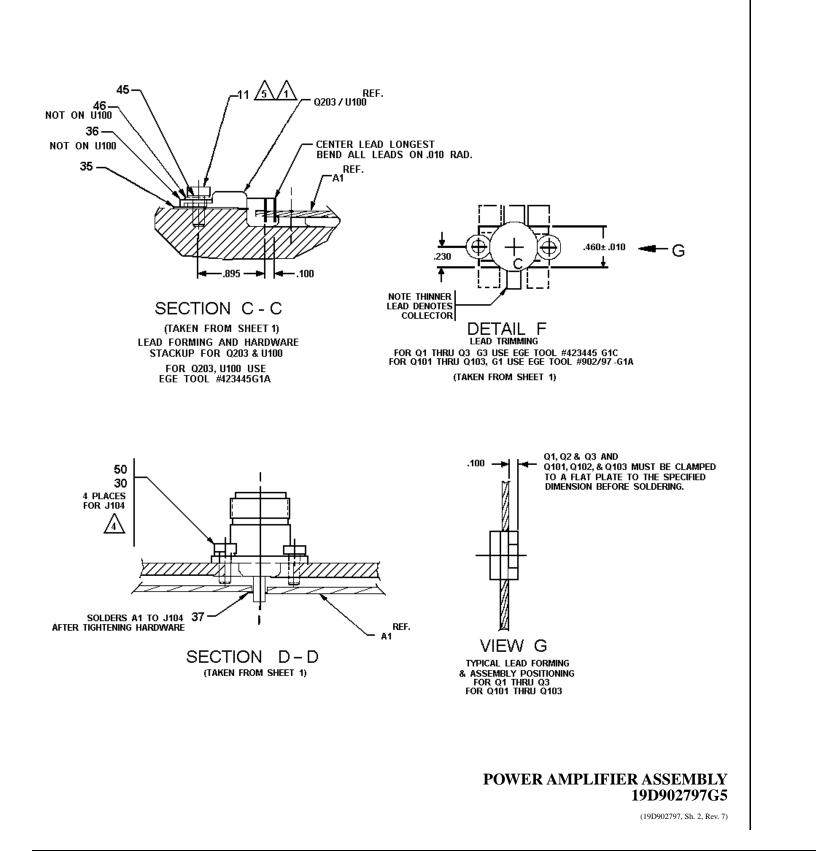
PARTS LIST

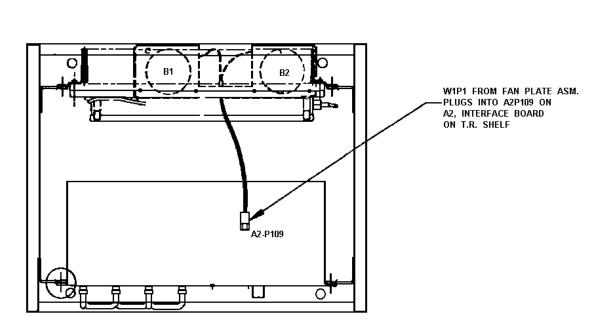
POWER AMPLIFIER 19D902797G5

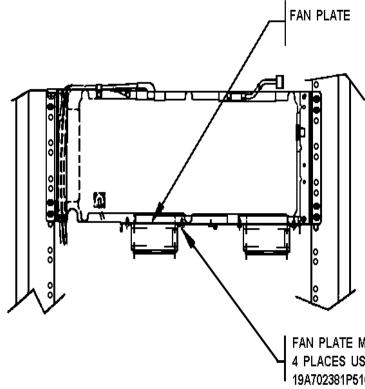
A1 Power Amplifier Board 190902794G5 AT1 REPUA01501/1 Attenuation: 20dB + or -1 dB 50 phms. C1 19A116708P2 Feedthu:: 0.01 uP + for -1 dB 50 phms. C1 19A116708P2 Feedthu:: 0.01 uP + for -6%, 500 VDCW; sim to Eric 327-050 -XW0103P. C1 19A702032P26 Ceramic: 0.1 uF + or -10%, 50 VDCW; sim to Eric 327-050 -XW0103P. C10 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 101J T500X. C11 19A702052P26 Ceramic: 0.1 uF + or - 10%, 50 VDCW. C12 and C13 344A3126P28 Porcelain: 100 pF + or - 5%, 50 VDCW; sim to 102JT500X. C14 and C15 19A702052P26 Coramic: 0.1 uF + or - 10%, 50 VDCW; sim to 101JT500X. C14 and C15 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 101JT500X. C16 and C17 RJE5843358/15E Tantalum: 15 uF + or -10%, 35 VDCW C18 thru U22 RJE5843358/15E Tantalum: 15 uF + or -10%, 50 VDCW.
AT1 REPUA01501/1 Attenuation: 20dB + or - 1 dB 50 phms. C1 19A116708P2 Feedthm: 0.01 uP + 100 - 0%, 500 VDCW; sim to Eric 327-060 - XW0103P. C1 19A116708P2 Feedthm: 0.1 uP + 100 - 0%, 500 VDCW; sim to Eric 327-060 - XW0103P. C1 19A702032P26 Ceramic: 0.1 uP + or - 10%, 50 VDCW. C9 C10 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 101JT500X. C11 19A702052P26 Ceramic: 0.1 uF + or - 10%, 50 VDCW. C12 344A3126P26 Ceramic: 0.1 uF + or - 10%, 50 VDCW. C13 19A702052P26 Coramic: 0.1 uF + or - 10%, 50 VDCW. C14 19A702052P26 Coramic: 0.1 uF + or - 10%, 50 VDCW. C13 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW. C14 19A702052P26 Coramic: 0.1 uF + or - 10%, 50 VDCW. C15 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW. C16 344A3126P38 Porcelain: 100 pF + or - 10%, 50 VDCW. C15 344A3126P38 Porcelain: 100 pF + or - 10%, 50 VDCW. C16 344A3126P38 Porcelain: 100 pF + or - 10%, 50 VDCW. C18 RJE5843358/15E Tanta
AT1 REPUA01501/1 Attenuation: 20dB + or - 1 dB 50 phms. C1 19A116708P2 Feedthn:: 0.01 uP + 100 - 0%, 500 VDCW; sim to Erio 327-060 - XW0103P. C1 19A702032P26 Ceramic: 0.1 uF + or - 10%, 50 VDCW. C1 19A702032P26 Ceramic: 0.1 uF + or - 10%, 50 VDCW. C10 344A3126F38 Porcelain: 100 pF + or - 5%, 500 VDCW, sim to 101JT500X. C11 19A/02052P26 Ceramic: 0.1 uF + or - 10%, 50 VDCW. C12 344A3126F28 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 102JT500X. C14 19A702052P26 Coramic: 0.1 uF + or - 10%, 50 VDCW. C13 344A3126F38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 102JT500X. C14 19A702052P26 Coramic: 0.1 uF + or - 10%, 50 VDCW. C15 344A3126F38 Porcelain: 100 pF + or - 5%, 500 VDCW. C15 344A3126F38 Porcelain: 100 pF + or - 10%, 50 VDCW. C16 344A3126F38 Porcelain: 100 pF + or - 5%, 500 VDCW. C16 344A3126F38 Porcelain: 100 pF + or - 10%, 35 VDCW. C17 C18 RJE5843358/15E Tantalum: 15 uF + or - 10%, 35 VDCW. C23 19A702052P26
C1 19A116708P2 Feedfhru: 0.01 uP + 100 - 0%, 500 VDCW; sim to Eric 327-050 - XW0103P. C1 thru C9 19A702052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW. C10 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 101JT500X. C11 19A/02052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW. C12 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 101JT500X. C13 344A3126P62 Porcelain: 1000 pF + or - 5%, 50 VDCW; sim to 102JT500X. C14 19A702052P26 Coramic: 0.1uF + or - 10%, 50 VDCW. C15 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 102JT500X. C14 19A702052P26 Coramic: 0.1uF + or - 10%, 50 VDCW. C16 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW. C16 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW. C17 S44A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW. C18 RJE5843358/15E Tantalum: 15 uF + or - 10%, 35 VDCW. C23 19A702052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW.
C1 thru C9 19A702032P26 Ceramic: 0.1uF + or - 10%, 50 VDCW. C10 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW, sim to 101/UT500X. C11 19A/02052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW. C12 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW, sim to 101/UT500X. C11 19A/02052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW. C12 and C13 344A3126P38 Porcelain: 100 pF + or - 5%, 50 VDCW; sim to 102/UT500X. C14 and C15 19A702052P26 Coramic: 0.1uF + or - 10%, 50 VDCW. C16 and C17 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW. C16 and C17 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW. C16 and C17 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW. C16 and C17 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW. C18 and C17 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW. C18 and C17 344A3126P38 Ceramic: 0.1uF + or - 10%, 35 VDCW.
thru Porcelain: 100 pF + or - 5%, 500 VDCW; sim to C10 344A3125P38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to C11 19A702052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW. C12 344A3126P62 Porcelain: 1000 pF + or - 5%, 50 VDCW; sim to C13 344A3126P62 Porcelain: 1000 pF + or - 5%, 50 VDCW; sim to C14 19A702052P26 Coramic: 0.1uF + or - 10%, 50 VDCW. C14 19A702052P26 Coramic: 0.1uF + or - 10%, 50 VDCW. C16 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to C16 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to C17 RJE5843358/15E Tantalum: 15 uF + or - 10%, 35 VDCW C18 HJA702052P28 Ceramic: 0.1uF + or - 10%, 50 VDCW.
C11 19A/02052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW. C12 344A3126F62 Porcelain: 1000 pF + or - 5%, 50 VDCW; sim to 102JT500X. C14 19A702052P26 Coramic: 0.1uF + or - 10%, 50 VDCW. C15 344A3126F93 Coramic: 0.1uF + or - 10%, 50 VDCW. C16 344A3126F936 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 101JT500X. C16 344A3126F936 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 101JT500X. C17 RJE5843358/15E Tantalum: 15 uF + or - 10%, 35 VDCW C23 19A702052F26 Ceramic: 0.1uF + or - 10%, 50 VDCW.
C12 and C13 344A3126P62 Porcelain: 1000 pF + or - 5%, 50 VDCW; sim to 102J7500X. C14 and and C15 19A702052P26 Coramic: 0, 1uF + or - 10%, 50 VDCW. C16 and C17 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 101J7500X. C18 and C17 RJE5843358/15E Tantalum: 15 uF + or - 10%, 35 VDCW C18 thru C22 19A702052P26 Ceramic: 0, 1uF + or - 10%, 50 VDCW.
and C13 102JT500X. C14 and C15 19A702052P26 Coramic: 0, 1uF + or - 10%, 50 VDCW. C16 and C17 344A3126P38 344A3126P38 Parcelain; 100 pF + or - 5%, 500 VDCW; sim to 101JT500X. C18 thru C22 RJE5843358/15E Tantalum: 15 uF + or - 10%, 35 VDCW C23 19A702052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW.
and C15 344A3125P36 Hercelain: 100 pF + or - 5%, 500 VDCW; sim to 101JT500X. C16 and C17 RJE5843358/15E Tantalum: 15 uF + or - 10%, 35 VDCW C18 thru C22 19A702052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW.
and C17 101JT500X. C18 thru C22 RJE5843358/15E Tantalum: 15 uF + or - 10%, 35 VDCW C23 19A702052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW.
thru C22 C23 19A7 02052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW.
C24 19A702052P5 Ceramic: 1000 pF + or -10%, 60 VDCW. and C25
C26 19A705108P25 Mica Chip: 33 pF + or -5%, 500 VDCW, temp coef 0 + 50 PPM/C.
C27 19A702052P5 Ceramic: 1000 pF + or -10%, 50 VDCW. thru C32
C33 19A705108P25 Mica Chip: 33 pF + or -5%, 500 VDCW, temp coef thru C39
C40 19A702052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW.
C41 19A705108P25 Mica Chip: 33 pF + or -5%, 500 VDCW, temp coef 0 + 50 PPM/C.
C42 19A702052P26 Ceramic: D.1uF + or - 10%, 50 VDCW.
C43 344A3126P203 Porcelain: 1.2uF + or - 0.25 pF, 500 VDCW; sim to and 1R2CT500X. C44
C46 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to thru C53 101JT500X.
C59 RJE5843358/15E Tantalum: 15 uF + or - 10%, 35 VDCW and C80
CG1 19A705205P18 Tantalum: 4.7uF + or - 20%, 35VDCW
C63 RJE5843358/15E Tantalum: 15 uF + or - 10%, 35 VDCW thru C68
C7 RJE5843358/15E Tantalum: 15 uF + or - 10%, 35 VDCW
C/9 19A705109P25 Mica Chip: 33 pF + or -5%, 500 VDCW, tomp coef thru C91 0 + 50 PPM/C,
C82 344A3126P38 Porcelain: 100 pF + or - 5%, 500 VDCW; sim to thru C85
C93 RJE5843358/15E Tantalum: 15 uF + or - 10%, 35 VDCW
C10 19A702236P36 Ceramic: 27 pF + or -5%, 50 VDCW, temp coef 0 + and C102 or -30 PPM/C.
C103 19A702052P26 Ceramic: 0.1uF + or - 10%, 50 VDCW
C104 19A702236P10 Ceramic: 2.2 pF + or -2.5 pF, 50 VDCW, temp or -50 PPM/C.
C105 19A/02236P36 Ceramic: 27 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/C.

SYMBOL	PART NO.	DESCRIPTION
C106 thru C108	344A3126P38	Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 101,7T500X.
C109	344A3126P1	Porcelain: 3.3 pF ⊫or - 0.25 pF, 500 VDCW; sim to 3R3CT500X.
C110	344A3126P203	Porcelain: 3.3 pF + or - 0.25 pF, 500 VDCW; sim to 3R3C1500.
C111 and C112	344A3126P98	Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 101JT500X.
C113	19A705108P25	Mica Chip: 33 pF ∈ or -5%, 500 VDCW, temp coef 0 ⊭ 50 PPM/°C.
C201	19A702061P37	Ceramic: 33 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/C.
C202	19A702052P26	Ceram(c: 0.1uF + or - 10%, 50 VDCW.
C203	19A702061P37	Ceramic: 33 pF + or - 5%, 50 VDCW, temp coef 0 + or -30 PPM/C.
C205 Ihru C207	19A702052P26	Ceramic: 0.1uF + or - 10%, 50 VDCW.
C208 Ihru C211	19A702061P37	Ceramic: 33 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/C.
C213	344A3126P38	Porcelain: 100 pF i or - 5%, 500 VDCW; sim to 101JT500X.
C214	19A702052P26	Ceramic: 0.1uF + or - 10%, 50 VDCW.
C215	RJE5843358/15E	Tantalum: 15 uF + or - 10%, 35 VDCW
C216	344A3126P38	Porcelain: 100 pF + or - 5%, 500 VDCW; sim to 101JT500X.
C217	19A702052P26	Ceramic: 0.1uF + ar - 10%, 50 VDCW.
C224	19A702052P26	Ceramic: 0.1uF + or - 10%, 50 VDCW.
C225	344A3126P38	Porcelain: 100 pF + or - 5%, 500 VDGW; s/m to 101JT500X.
C226	RJE5843358/15E	Tantalum: 15 uF + or - 10%, 35 VDCW
C227	19A702052P26	Ceramic: 0.1uF + or - 10%, 50 VDCW
		DIODES
D1 thru D5	19A700053P3	Silicon: 2 Diodes in Series, Common Cathodo; sim to MBAV70L.
D6 thru D8	19A705377P4	Silicon, Hot Carrier; sim to HSMS-2802.
1) 9	RKZ12303/1	Diode, silicon, FILTERS
E 14	DE0.20400/0	
FL1 thra FL7	REG70420/2	Ferrite, bead.
FL10	RTNUA50101/1	Low Pass: (Used in 860-960 MHz).
J101	19A705512P1	Connector, RF SMB Series: sim to AMP No. 221111-1.
J101	RNT403185/02	Connection, RF; SMD 50 ohms.
J103	19A134263P1	Contact, electrical: sim to Selectro 229-1082-00-0-590.
J104	7777145P5	Receptacle: sim to Amphenol 82-97.
J201	19A704852P32	Printed wire, two part: 6 contacts, sim to Molex 22-29-2061.
		INDUCTORS
L1 thru L3	19A705470P13	Coil: 0.10 uH + or -20%.
£101	344A3678P8R2	Coil, Fixed; RF SM.
L10	19A705470P9	Coil, Fixed: 47 nH; sim to Toko 360NB-47nM.
L201	19A705470P13	Coll: 0.10 uH + or -20%.
L202		
Q1 and Q2	19A700076P2	Silicon, NPN: sim to MMBT3904, low profile.

			SYMBOL	PART NO.	DESCRIPTION
SYMBOL	PART NO.	DESCRIPTION	R53	19A702931P137	Metal film: 237 ohms + or .5%. 1/8w.
Q3	19A134577P2	Silicon, PNP: sim to Philips BCX51-16.	R101	19B800607P330	Metal film: 33 ohms + or -5%. 1/8w.
Q4	BYN121634/1	Silicon, Power, SMD.	R102	19B800607P270	Metal film: 27 ohms + or -5%. 1/8w.
Q55	RYN121655/1	Power: 150W.	R103	19B800607P330	Metal film: 33 ohms + or -5%. 1/8w.
Q6	FIYN121634/1	Silicon, SMD.	R201	19B800607P102	Metal film: 1K ohms + or -5%. 1/8w.
arid Q7			R202	19B800607P103	Metal film: 10K ohms + or -5%. 1/8w.
		RESISTORS	R203	19B800607P473	Metal film: 47K ohms + or 5%. 1/8w.
H1 thru D4	REL316214/5	Potontiameter: 5K, 10T SMD.	R204	REL316215/5	Potentiometer: 5K, 10T SMD
R5 thru	19B800607P103	Motal film: 10K ohms + or -5%, 1/8 w.	RT1	19A705813P2	Thermistor: sim to AL03006-58.2K-97-0100.
R7 R8	19B800607P681	Metal film: 680 ohms + or -5%, 1/8 w.	U1	19A701789P4	Linear: Quad Op Amp: sim to LM224D.
R9	19B800607F472	Metal film: 4.7K ohms + or -5%, 1/8 w.		RYT9016074/1	
H10	19B600607P270	Metal film: 27 ohms + or -5%, 1/8 w.	U2 U3	19A701789P4	Power : RF.
R11 and	19B800607P103	Metal film: 10K ohms + or -5%, 1/8 w.	U4 and	19A701789P4	Linear: Quad Op Amp: sim to LM224D. Voltage Regulator, 8V: sim to MC/8M08CDT.
R12	(00000077D070)		U5		
R13 914	196800607P270 196800807P330	Metal film: 27 ohms + or -5%, 1/8 w. Matal film: 23 ohms + or -5%, 1/8 w.	U6	UNK10243/01	Circulator: 150W.
R14 ក15	19B800607P360	Metal film: 33 ohms + or -5%, 1/8 w. Metal film: 10K ohms + or -5%, 1/8 w.	U7	RYT1136080/1	Volt Regulator.
R16	(9B901486P101	Metal film: 100 ohms + or -5% , 1/2w.	U101	RYT1016155/1	MMIC.
B17	19B800607P103	Metal film: 106 ohms + or 5%, 1/8 w.			VOLTAGE REGULATORS
R19	19B900607P822	Metal film: 8,2K ohms + or -5%, 1/8 w.	VR1	19A700063P102	Silicon: 5.1 Volt Zener; sim to BZX84-C5V1.
R19	19B800607P103	Metal film: 10K ohms i or -5%, 1/8 w.	W1	19B803978P1	Cable RF.
thru			W4	19B801695G11	Cable.
R21 R22	19B800607P472	Metal tilm: 4.7K ohms + or - 5%, 1/8 w.			MISCELLANEOUS
H23	19B800607P103	Metal film: 10K ohns + or -5%, 1/8 w.	5	19A702381P510	Screw,thread forming: TORX DRIVE No. M3.5-
thru H25	190000071 100	Metal IIIII. Tox Official 4 di -576, 178 W.			0.6 x 10.
FI26	19B800607P220	Metal film: 22 ohms + or -5%, 1/8 w.	6	7139898P3	Nut, hex, brass: No. 1/4-28.
R27	19B800607P222	Metal film: 2.2K ofms + or -5%, 1/8 w.	7	19D902420P7	Heatsink.
R28	19B800607P22D	Metal film: 22 ohms + or -5%, 1/8 w.	9	19A702339P510	Screw.
R29	19B801486P101	Metal film: 100 phms ⊩ or - 5%, 1/2w.	11	19A702364P510	Machine screw.
R30	19B8006079510	Metal film: 51 ohms + or -5%, 1/8 w.	14	19B209268P113	Terminal, solderless: sim to AMP 2-34835-4.
R31	198600607P472	Motal film: 4.7K ohms + or -5%, 1/8 w.		19A115959P2 19B209268P116	Wire stranded.
R32	19B800607P510	Metal film: 51 ohms + or -5%, 1/8 w.	16	196209266P116 19A700136P7	Solderless terminal.
R33	198800607P103	Metal film: 10K ohms + or -5%, 1/8 w.	16		Insulated sleeving.
R34	198800607P472	Metal film: 4.7K ohros + or -5%, 1/8 w.	21 22	19A701863P27 19A701312P5	Clip, loop.
R35	198801486P750	Metal film: 75 ohms + or - 5%, 1/2w.	22	19A701312P3 19A702364P316	Flatwasher: M3.5. Machine Screw: Pan Head, Steel, (Used in 65, 610)
R36	19B800607P750	Metal film: 75 ohms + or -5%, 1/8 w.	28	19A702364P316 19A700034P4	Machine Screw:Pan Head, Steel. (Used in G5, G10). Nut, hex:No. M3x0.5MM. (Used in G5, G10).
R37 and R38	19B801486P330	Metal film: 33 ohm + or -5%, 1/2 w.	30	19A700032P5	Lockwasher,internal tooth:No. 3MM. (Used in G5 and G10).
H39	19R800607P101	Metal film: 100 ohms + or -5%, 1/8 w.	37	19A134455P3	Washer, flat.
R40	19B801486P330	Metal film: 33 ohms + or -5%, 1/2 w.	38	19B801659G4	Cover.
R41	19B801486P270	Metal film: 27 ohms + or - 5%, 1/2 w.	41	19A700033P6	Lockwasher, external tooth, M3.5.
R42	19B800607P472	Metal film: 4.7K ohms + or -5%, 1/8 w.	45	N405P5B6	Lockwasher.
R43	19B801486P330	Metal film: 33 ohm + pr -5%, 1/2 w.	46	19A701312P4	Flatwasher: 3.2 ID.
FI44	19B800607P102	Metal fi(m: 1K ohms + or -5%, 1/8 w.	50	19A702381P408	Tap screw, TORX Drive, M3-0.5x8.
R45	19A702931P285	Metal film: 7.5 K ohms + or -1%, 200 VDCW, 1/8w,	63	19B803982P1	Plate.
R46	19A702931P333	Metal film: 21.5K ohms + or -1%, 200 VDCW, 1/8w.	65	19D902420P7	Heatsink.
R47	19B800607P151	Metal tilm: 150 ohms + or -5%, 1/8 w.	70	19B804034P1	Plate, spacer.
H48	REL316214/5	Patentiometer: 5K, 10T SMD.	75	N404P25	Lockwasher.
R49	19B800607P103	Metal film: 10K ohms + or -5%, 1/8 w.	W10	19B801937P1	Power cable.
R50 and R51	19B800607P101	Metal film: 100 ohms + or -5%, 1/8 w.	W13	19B801739P1	Cable, Control.
R52	19A702931P258	Metal film: 3920 ohms i k or -1%, 200 VDCW, 1/8 w.			







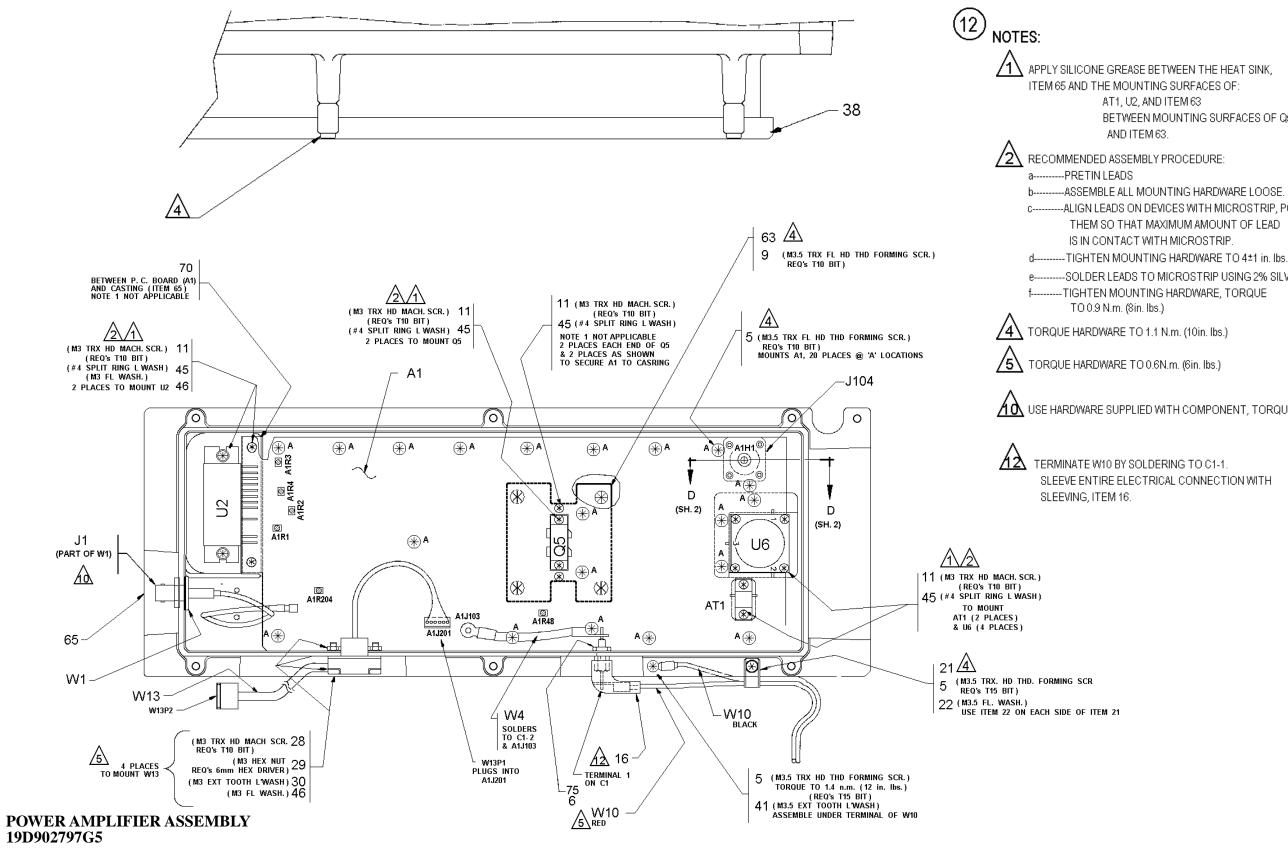
FRONT VIEW

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FAN PLATE MOUNTED TO BOTTOM OF P.A. 4 PLACES USING M3.5 X 10 THREAD FORMING SCREWS 1 19A702381P510 OR EQUIVALENT (REQ'S T15 BIT)

PA FAN PLATE ASSEMBLY 188D6127G1

(188D6131, Rev. 1)



(19D902797, Sh. 4, Rev. 8)

BETWEEN MOUNTING SURFACES OF Q5

-----ALIGN LEADS ON DEVICES WITH MICROSTRIP, POSITIONING THEM SO THAT MAXIMUM AMOUNT OF LEAD ----SOLDER LEADS TO MICROSTRIP USING 2% SILVER ----- TIGHTEN MOUNTING HARDWARE, TORQUE

10 USE HARDWARE SUPPLIED WITH COMPONENT, TORQUE TO 0.6 N.m. (6in. lbs.)

TROUBLESHOOTING GUIDE

SYMPTOM	AREAS TO CHECK	INDICATIONS
 No power or low power at An- tenna Port. 	 Measure the transmitter output power before the duplexer or antenna switch (for simplex mode). 	The presence of power at this port is an indication of a defective duplexer, switch, or cables.
	2. Measure the transmitter output power before the low pass filter.	The presence of power at this port is an indication of a defective filter or cables.
 No power at PA output port and PA ALARM is OFF. 	1. Station is in receive mode.	
3. No power at PA output port and PA ALARM is ON.	 No RF input to the PA. Check connection between PA and TX Synthesizer. 	TX Synthesizer should deliver a minimum of 10 mW (10dBm) to the PA.
	Check the logic or DC inputs to the PA from the Interface Board through J201.	
	a. J201-PA KEY	5 volts during transmit
	b. J201-3 POWER SET	4 volts to 8 volts (4 volts represents zero RF
	c. J201-6 13.8 VF	13.8 Vdc ±20%
	3. Check the bias voltage on the base of Q5.	Voltage should be .73V nominal.
	 Check the bias voltage at module U2. pin 2 pin 4 pin 6 pin 8 	Voltages should be: 14-18V nominal 14-18V nominal 0.7V nominal 0.7V nominal
	Note: There is no pin 3 on module U2. Pin 4 is the 3rd pin physically.	
 Low power at PA output port and PA ALARM is OFF. 	1. Low RF input to PA from TX Synthesizer.	Power should be a minimum of 10 mW (10 dBm).
	2. Check the voltage on J201-3 (POWER SET).	For nominal output power, this voltage should be above 7 volts.
	 Check the power supply voltage on the collector of Q5. 	Voltage should be nominal 26.0 Vdc.
	4. Check the bias voltage on the base of Q5.	Voltage should be .73V nominal.
	 Check the bias voltage at module U2. pin 2 pin 4 pin 6 pin 8 	Voltages should be: 14-18V nominal 14-18V nominal 0.7V nominal 0.7V nominal
	Note: There is no pin 3 on module U2. Pin 4 is the 3rd pin physically.	
 Low power at PA output port and PA ALARM is ON. 	 Check for over temperature and/or a high VSWR condition due to a mismatch at the output port. 	The power control circuit protects the PA by cutting back the power. In case of a mismatch, refer to symptom 1.

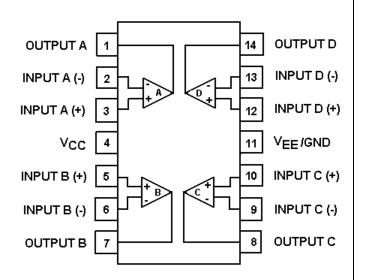
800 MHz POWER AMPLIFIER VOLTAGE CHART

PARAMETER (50 ohm, -30°C to +60°C)	REFERENCE SYMBOL	READINGS (volts DC)
SUPPLY VOLTAGE	A+	26.0 +5, - 20%
CONTROL VOLTAGE	Vctl	0-2V
FORWARD VOLTAGE	Vf	4-5V
REVERSE VOLTAGE	Vr	2-4V
POWER SENSE	J201-1	2.5 - 4V
PA KEY	J202-2	5V
POWER SET	J202-3	4 - 8V
13.8 VF	J201-6	13.8V ±20%

RATED POWER FOR MASTR III 800 MHz BASE STATION

FREQUENCY MHz	STANDARD	ADJUSTABLE RANGE
851-870	100W, AFTER LOW PASS FILTER	10-100W, AFTER LOW PASS FILTER

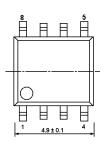
IC DATA



U3, U1 19A701789P4 Quad Op-Amp

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Terminal	Function
1	Ground and thermal contact
2	Vcc1
3	Ground
4	RF
5	Power control
6	RF _{OUT} and Vcc2
7	Ground and thermal contact
8	Ground and thermal contact



U101 RYT1016155/1

PA Output Power Set

PA output power is set according to the level of the Power Set line. Four (4) volts on this line will produce minimum power. As the voltage increases toward eight (8) volts, the power will increase to the maximum rated output. The PA output power is initially set for an output of 110 watts at J104. This is done by adjusting R204 while injecting a 10 mW signal at J1 and applying 8 volts to J201-3. After setting the maximum power level, changing the output power is done by varying the voltage applied on the Power Set line.

PA Protection

The power control also protects the PA against over temperature and high VSWR conditions.

An over temperature condition exists when the flange temperature of the final output transistor reaches 80°C. At this point the output power will drop below its set level. The output power will continue to drop such that when the flange temperature reaches 125°C the PA output drops at least 10 dB below its set level.

Reflected power is limited to 25% of the set power. If the output VSWR degrades to worse than 3:1 the forward power will be reduced to limit the reflected power to 25% of the set power. The Power Sensor line indicates when the PA is operating in a cutback condition. If the PA is keyed and the power control is cutting back, the Power Sensor line will drop to zero (0) volts and the PA alarm light on the station will turn on.

Power Monitor

A DC voltage proportional to forward power, provided by the detection circuit of the Power Sense stage, is buffered and delivered to the PWR Monitor line of the interface connector.

Theory Of Operation

Power control of the MASTR III Power Amplifier is accomplished with a feedback control loop. The three possible feedback signals are: representation of forward power, temperature sensitive scaled representation of forward power, or representation of reflected power. The three signals are input to a diode summing junction which selects the largest of the three for use as the feedback.

The microstrip directional coupler samples the output power and produces a voltage, Vf, proportional to the forward output power. The power control compares the forward voltage, Vf, to a reference voltage at U3. The output of U3 adjusts the control voltage at pin 5 of the MMIC of the Small Signal Gain Stage. This varies the gain through the stage, and controls the power output level of the Power Amplifier Assembly.

During over temperature operation, a scaled representation of the forward power is maintained constant by varying the control voltage line. Thermal resistor RT1 sensing an increase in temperature causes the output of U1.1 to increase. If the output of U1.1 becomes larger than the other feedback lines, the output of U3.2 will begin to decrease. This causes the gain of U101 to decrease. Since the scaling is a function of temperature the power is reduced as the temperature increases.

Under VSWR cutback operation the reverse voltage, Vr, representative of the reflected output power is held below a threshold by reducing the control voltage as necessary. If Vr increases at U1.2 beyond the preset threshold an increase at U3.2 will result. This causes a subsequent reduction in the control voltage to U1. Thus the power control circuit reduces the output power in order to limit the reflected power to 25% of the set power.

Signal Interface

The signal interface to the MASTR III Power Amplifier is supported by a six position feedthrough connector, J201, with the following pinout:

- 1 PWR Sensor
- 2 PA Key
- 3 PA PWR Set
- 4 PWR Monitor
- 5 Ground
- 6 Fil A+

Pwr Sensor

This line indicates when the PA is experiencing adverse conditions. Under normal operation, while the PA is keyed, this line will be proportional to forward power. Minimum power (zero watts) corresponds to 2.5 volts while maximum power corresponds to 4.5 volts. This voltage is not temperature compensated and no effort is made to calibrate this signal to an absolute power level. It is intended to provide a relative indication of forward power and to discriminate between normal and cutback operation.

Zero volts on this line, when the PA is keyed, indicates the forward power is cutback. This power cutback may be due to high reflected power or may be due to high PA temperatures. This fault condition may indicate a problem with the PA or may indicate a system problem external to the Power Amplifier. High VSWR may be due to a poor antenna and high temperature may be due to a blocked cabinet vent. Zero volts on this line, when the PA is keyed, does not indicate zero forward power. Zero volts indicates the PA is protecting itself due to adverse conditions. If the adverse condition, either high VSWR or high temperature is eliminated, the power will return to normal and the PWR SENSOR voltage will rise above 2.5 volts.

PA Key (Interface Connector Pin 2)

This line is used to key and unkey the PA, UNKEY=0 volt and KEY=5 volts. The driver of this line must be capable of supplying 5 volts at 1.0 mA. The appropriate key sequence requires RF from the transmit synthesizer be input to the PA before the KEY line is energized.

PA PWR Set (Interface Connector Pin 3)

This line is used to set the RF Power Output of the PA. Minimum power output equals 4 volts and maximum power output equals 8 volts. The driver of this line must be capable of supplying 8 volts at 1.0 mA.

Fil A+ (Interfaces Connector Pin 6)

This line provides the filtered supply voltage for the Power Control. The driver of this line must be capable of supplying 13.4 volts $\pm 20\%$ at 100 mA.

PWR Monitor

This line provides a DC voltage proportional to forward power.

ITEM SPECIFICATION FREQUENCY 851-870 MHz **OUTPUT POWER (RF)** 11 TO 110 W @ J104 10 mW min. into <2:1 VSWR **INPUT POWER (RF)** TEMPERATURE RANGE -30° C to $+60^{\circ}$ C (Ambient air) SUPPLY VOLTAGE 26.0V CURRENT 14A max. (11 A typical @ 110W, 26.0 V) DUTY CYCLE Continuous STABILITY Stable into 3:1 VSWR; all temp., voltage, FREQ. 11-110W RUGGEDNESS AT HIGH VSWR No damage into open or shorted load

Table 1 - General Specifications

The Power Control circuitry sets the output power level by adjusting the PA Power Set level. It keeps the output power constant despite variations in input power, power amplifier gain, or temperature through the use of a feedback control loop in the PA assembly.

CIRCUIT ANALYSIS

POWER AMPLIFIER

The power amplifier section of the PA Board consists of a Small Signal Gain Stage, a Driver Module, a Final Power Stage, and Power Sense and Isolation Stages. All these gain stages have an input and output impedance of 50 ohms. Figure 1 is a block diagram showing the signal flow within the Power Amplifier Assembly.

Small Signal Gain Stage (U101)

This stage uses a broadband silicon monolithic microwave integrated circuit (MMIC) amplifier. The signal from transmitter synthesizer, typically 10 dBm (10 mW), is input through a 10 dB resistive pad (R101, R102, and R103). The stage amplifies the resulting 0 dBm (1 mW) signal to the necessary level to achieve desired PA output power (typical +5 dBm for 110W out).

Bias for the MMIC is supplied by an 8V regulator (U4). This voltage is DC coupled to pin 6 and is supplied through a dropping resistor, R43, for pin 2. Power control for the Power Amplifier Assembly is performed by controlling the RF level out of the MMIC by varying the control voltage at pin 5.

Driver Module (U2)

The Driver Module is a 35 dB gain, 4-stage, linear hybrid amplifier. The first two stages of the module are identical FET amplifiers, class A biased to provide maximum gain. Stages 3 and 4 are bipolar transistors, class AB biased to provide maximum saturated power and efficiency. The quiescent current of these stages is set by variable resistors R1, R2, R4, and R3 respectively. Typical bias current for each stage is 100, 90, 90 & 90mA respectively.

CAUTION

These currents are factory set. Field adjustment is not recommended, and may result in device failure.

The voltage for the bias circuitry is supplied by U7, a voltage regulator. A transistor switch, O3, is used to apply this voltage when the unit is keyed. The nominal output power of this stage is 42.4 dBm (17.5W).

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The Final Power Stage of the unit consists of a push-pull pair of silicon bipolar power transistors mounted on a single flange, Q5, and its associated matching and bias circuitry. A quarter-wave transmission line transformer feeds a pair of 25 ohm lines in parallel, one of which is 180° longer than the other, to create a microstrip balun. The resulting balanced circuit is transformed by reactive components to match the input impedance of the final device. Similar circuitry is used on the output to match the device's output impedance. The quiescent current of transistor Q5 is set by variable resistor R48 for Class AB operation. Typical bias current is 400 mA for this stage.

CAUTION

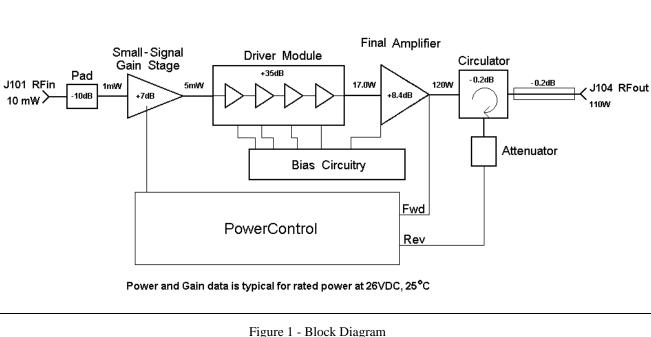
These currents	are factory set.	Field adjustment is not
recommended,	and may result i	n device failure.

The result is a typical 8.4 dB gain stage capable of producing a nominal 50.8 dBm (120W) of RF power.

Power Sense and Isolation Stages

Integrated into the output microstrip balun, an eighthwave directional coupler is used to sense the magnitude of forward power. D6, an active detector, is used to convert this level to a DC voltage proportional to forward power, and this voltage is sent to the power control circuitry.

Final Power Stage (Q5)



The third port of the circulator is terminated by a 20 dB power attenuator, AT1, followed by a resistive pad, R35, R36, R39. Any signal reflected back into the Power Amplifier Assembly is directed by the circulator through the pads, and is converted to a DC voltage by D7. This voltage is sent to the power control circuitry.

POWER CONTROL

The Power Control circuitry performs four basic functions. It keys and unkeys the PA, sets the PA output power. protects the PA against adverse conditions, and provides a voltage proportional to output power at the interface cable.

LBI-39127A

The amplified signal from the Final Power Stage is fed to U6. a circulator, to provide 20 dB typical isolation from load mismatches. The device insertion loss of 0.2 dB maximum, along with the microstrip trace losses, provide 50.4 dBm (110W) of RF power at the PA output, J104.

Keying And Unkeying The PA

To key the PA, the digital controller places 5 volts on the PA key line, J201-2. Zero volts on the PA key line causes the PA to unkey. If the control cable (W13) is disconnected, with nothing actively driving the PA key line, the PA will remain unkeved.